### Glass Passivated Junction Plastic Rectifier



## 1N4007GP-HF

Voltage: 1000 V Current: 1.0 A

**RoHS Device Halogen Free** 

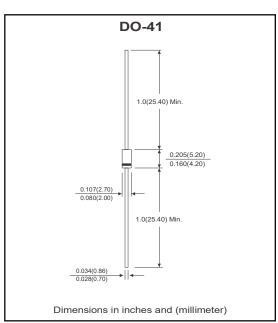
#### **Features**

- \* High reliability
- \* Low leakage
- \* Low forward voltage drop
- \* High current capability
- \* Glass passivated junction

#### Mechanical data

- \* Case: Molded plastic \* Epoxy: Device has UL flammability classification 94V-O \* Lead: MIL-STD-202E method 208C guaranteed \* Mounting position: Any \* Weight: 0.33 gram





#### Circuit diagram



### Maximum Ratings and Electrical Characteristics (at Ta=25°C unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load derate current by 20%.

Parameter	Conditions	Symbol	Value	Unit	
Maximum recurrent peak reverse voltage		V <sub>RRM</sub>	1000	V	
Maximum RMS voltage		VRMS	700	V	
Maximum DC blocking voltage		VDC	1000	V	
Maximum average forward rectified current	see figure 1	I <sub>(AV)</sub>	1	А	
Peak forward surge current	8.3mS single half sine-wave superimposed on rated load	Іғѕм	30	А	
Maximum instantaneous forward voltage	@I <sub>F</sub> = 1A	VF	1.0	V	
Maximum DC reverse current	T <sub>j</sub> = 25°C		0.2		
at rated DC blocking voltage	T <sub>j</sub> = 150°C	- IR	400	μA	
Typical junction Capacitance	V <sub>R</sub> = 4V, f = 1MHz	CJ	15	pF	
Typical thermal resistance	Junction to ambient	Roja	50	°C/W	
Operating junction temperature range		TJ	-65 ~ +175	°C	
Storage temperature range		T <sub>STG</sub>	-65 ~ +175	°C	

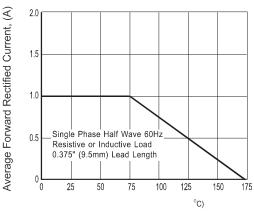
NOTES: Measured at 1 MHz and applied reverse voltage of 4.0 volts

Company reserves the right to improve product design, functions and reliability without notice.



#### Rating and Characteristic Curves (1N4007GP-HF)

Fig.1 - Forward Current Derating Curve



Ambient Temperature, (°C)

Peak Forward Surge Current, (A)

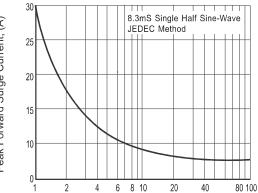


Fig.2 - Max. Non-Repetitive Peak Forward Surge Current

Number of Cycles at 60Hz

Fig.3 - Typical Instantaneous Forward Characteristics

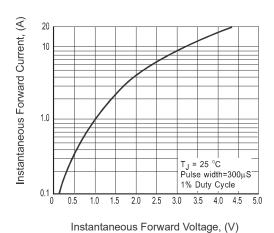


Fig.5 - Typical Junction Capacitance

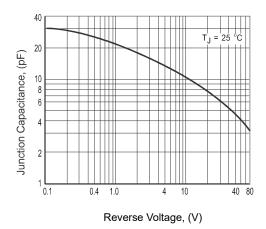
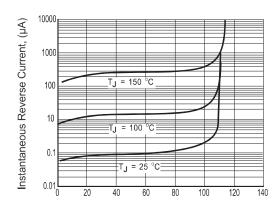


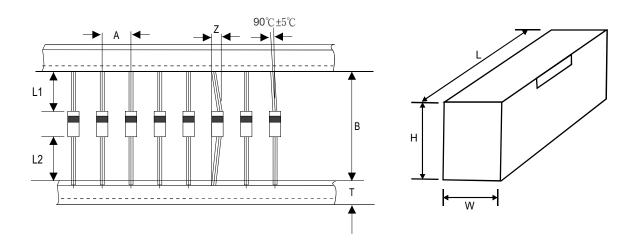
Fig.4 - Typical Reverse Characteristics



Percent of Rated Peak Reverse Voltage, (%)



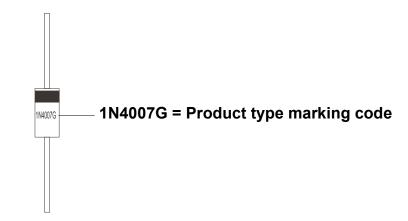
### **Taping Specification For Axial Lead Diodes**



	SYMBOL	Α	В	Z	Т	L1	L2
DO-41	(mm)	5.00 ± 0.50	52.00 ± 0.50	1.20 (max)	6.00 ± 0.40	1.00 (max)	1.00 (max)
	(inch)	0.197 ± 0.020	2.047 ± 0.020	0.047 (max)	0.236 ± 0.016	0.039 (max)	0.039 (max)
	•						
	SYMBOL	L	w	Н			
DO-41	SYMBOL (mm)	L 255.00 ± 10.00	W 73.00 ± 10.00	H 100.00 ± 10.00			

# **Marking Code**

Part Number	Marking Code
1N4007GP-HF	1N4007G



### **Standard Packaging**

	AMMO PACK		
Case Type	BOX (pcs)		
DO-41	3,000		

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Comchip Technology: 1N4007GP-HF